

[at%X]	Z [e/a]	T _c [K]	Ref	T _k [K]	Ref	r [mWcm]	Ref	1/r dr/dt [10 ⁻⁵ /K]	Ref	R _H [10 ⁻¹¹ m ³ /As]	Ref	S'(T)/T [nV/K ²]	Ref
14				417	1								
29				413	1								
30				421	1								
32				416	1								
35				433	1								
39				428	1								
43				433	1								
49				435	1								
50				440	1								
57				416	1								
60				413	1								
68				429	1								
71				465	1								
74				464	1								
79				474	1								
79				450	1								
83				424	1								

Caption:

- Z indicates the mean electron number per atom
 - T_c indicates the transition to the superconducting state
 - T_k indicates the crystallization temperature
 - ρ indicates the specific resistivity at T approx. 4K
 - 1/ρ dp/dt indicates the temperature coefficient at approx. T=100K
 - R_H indicates the Hallcoefficient at approx. T=10K
 - S'(T)/T indicates the slope of the thermopower at low T
- The horizontal thin lines enclose the amorphous range

References:

- [1] P. Haeussler

The concentration range between the thin horizontal lines shows the amorphous alloys, outside the samples are partly are completely crystalline.